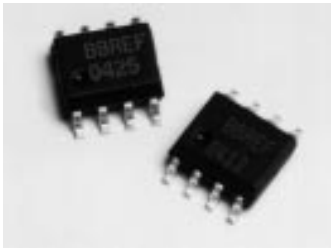
BURR-BROWN®



REF1004

1.2V and 2.5V Micropower VOLTAGE REFERENCE

FEATURES

- **INITIAL ACCURACY:**
  REF1004-1.2 ±4mV
  REF1004-2.5 ±20mV
- **MINIMUM OPERATING CURRENT:**
  REF1004-1.2 10μA
  REF1004-2.5 20μA
- **EXCELLENT LONG TERM TEMPERATURE STABILITY**
- **VERY LOW DYNAMIC IMPEDANCE**
- **OPERATES UP TO 20mA**
- **PACKAGE: 8-Lead SOIC**

APPLICATIONS

- **BATTERY POWERED TEST EQUIPMENT**
- **PORTABLE MEDICAL INSTRUMENTATION**
- **PORTABLE COMMUNICATIONS DEVICES**
- **A/D AND D/A CONVERTERS**
- **NOTEBOOK AND PALMTOP COMPUTERS**

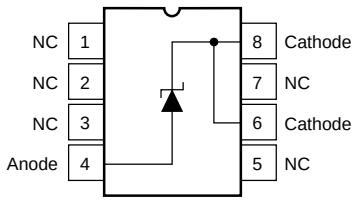
DESCRIPTION

The REF1004-1.2 and REF1004-2.5 are two terminal bandgap reference diodes designed for high accuracy with outstanding temperature characteristics at low operating currents. Prior to the introduction of the REF1004 Micropower Voltage References, accuracy and stability specifications could only be attained by expensive screening of standard devices. The REF1004 is a cost effective solution when reference voltage accuracy, low power, and long term temperature stability are required.

REF1004 is a drop-in replacement for the LT1004 as well as an upgraded replacement of the LM185/385 series references. The REF1004C is characterized for operation from 0°C to 70°C and the REF1004I is characterized for operation from –40°C to +85°C.

The REF1004 is offered in an 8-lead Plastic SOIC package and shipped in anti-static rails or tape and reel.

Typical Operating Circuit



(Top View)

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PDS-1172 Printed in U.S.A. October, 1993

SBVS002

SPECIFICATIONS

ELECTRICAL

T_A = +25°C unless otherwise noted.

PARAMETER	CONDITIONS	REF1004-1.2			REF1004-2.5			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
REFERENCE VOLTAGE	I_R = 100µA	1.231	1.235	1.239	2.490	2.500	2.511	V
REF1004C[1]		1.229	1.235	1.239	2.487	2.500	2.511	
REF1004I[2]		1.225	1.235	1.239	2.480	2.500	2.511	
AVERAGE TEMPERATURE COEFFICIENT	$I_{MIN} \le I_R \le$ 20mA		20			20		ppm/°C
MINIMUM OPERATION CURRENT[3]			8	10		12	20	µA
REVERSE BREAKDOWN VOLTAGE CHANGE WITH CURRENT	$I_{MIN} \le I_R \le$ 1mA			1			1	mV
				1.5[3]			1.5[3]	
	1mA $\le I_R \le$ 20mA			10			10	
				20[3]			20[3]	
REVERSE DYNAMIC IMPEDANCE[3]	I_R = 100µA		0.2	0.6		0.2	0.6	Ω
WIDE BAND NOISE (RMS)	I_R = 100µA							
10Hz $\le I_R \le$ 10kHz			60			120		µV
LONG TERM STABILITY	I_R = 100µA							
T_A = 25°C ± 0.1°C			20			20		ppm/KHr

NOTES: (1) This specification applies over the full operating temperature range of 0°C $\le T_A \le$ 70°C. (2) This specification applies over the full operating temperature range of 40°C $\le T_A \le$ +85°C. (3) Denotes the specifications which apply over the full operating temperature range.

ORDERING INFORMATION

MODEL	T_A	V_Z	PACKAGE
REF1004C-1.2	0°C to +70°C	1.2V	8-Lead SOIC
REF1004C-2.5	0°C to +70°C	2.5V	8-Lead SOIC
REF1004I-1.2	–40°C to +85°C	1.2V	8-Lead SOIC
REF1004I-2.5	–40°C to +85°C	2.5V	8-Lead SOIC

NOTE: Available in Tape and Reel, Add –TR to Model Number.

ABSOLUTE MAXIMUM RATINGS

Reverse Breakdown Current 30mA
Forward Current 10mA
Operating Temperature Range
  REF1004C ..... 0°C to +70°C
  REF1004I ..... –40°C to +85°C
Storage Temperature
  REF1004C ..... –65°C to +150°C
  REF1004I ..... –65°C to +150°C
Lead Temperature (soldering, 10s) ..... +300°C

ORDERING INFORMATION

MODEL	PART MARKING
REF1004C-1.2	BBREF0412
REF1004C-2.5	BBREF0425
REF1004I-1.2	BBREF0412
REF1004I-2.5	BBREF0425

PACKAGE INFORMATION

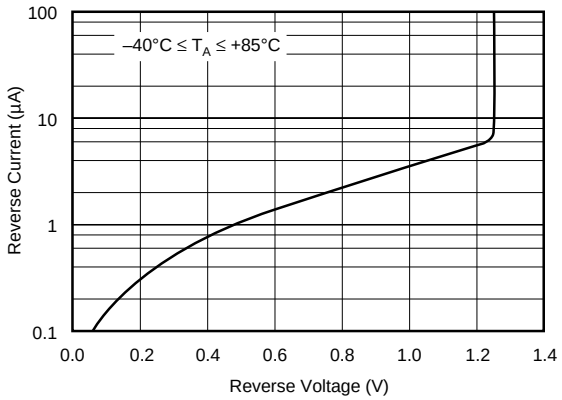
MODEL	PACKAGE	PACKAGE DRAWING NUMBER[1]
REF1004C-1.2	8-Pin SOIC	182
REF1004C-2.5	8-Pin SOIC	182
REF1004I-1.2	8-Pin SOIC	182
REF1004I-2.5	8-Pin SOIC	182

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix D of Burr-Brown IC Data Book.

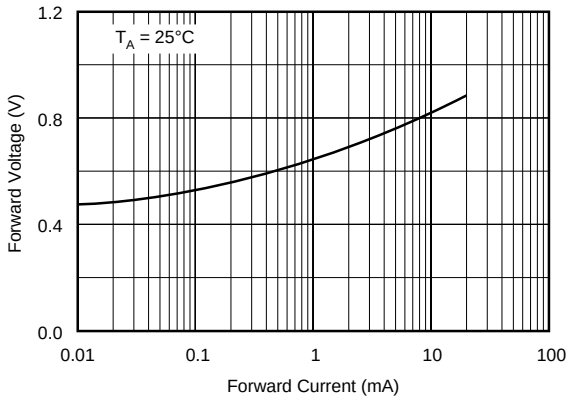
TYPICAL PERFORMANCE CURVES 1.2V

T_A = +25°C unless otherwise noted.

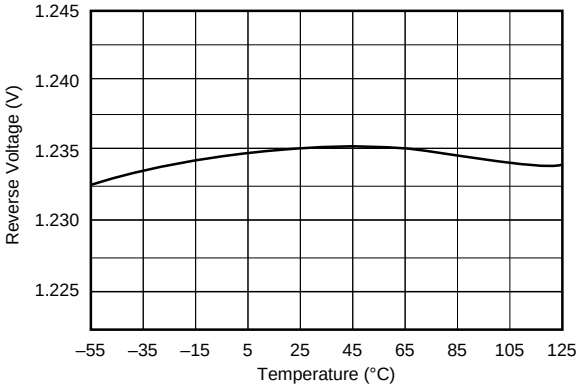
REVERSE CHARACTERISTICS



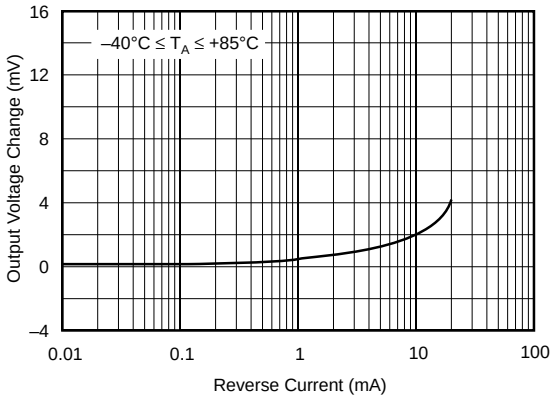
FORWARD CHARACTERISTICS



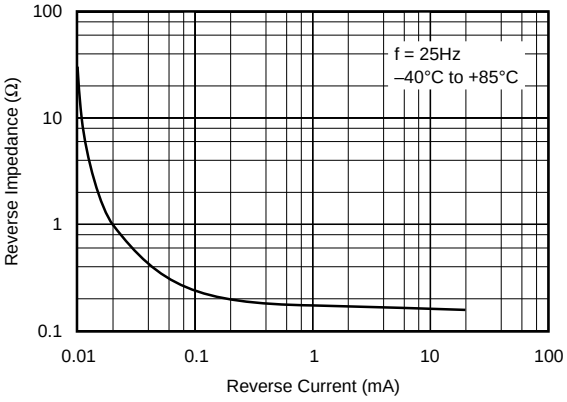
TEMPERATURE DRIFT



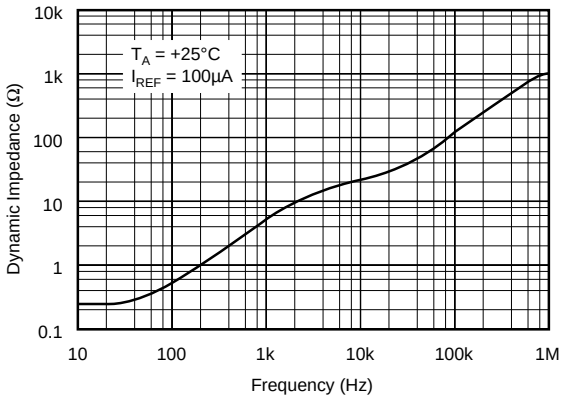
REVERSE VOLTAGE CHANGE



REVERSE DYNAMIC IMPEDANCE



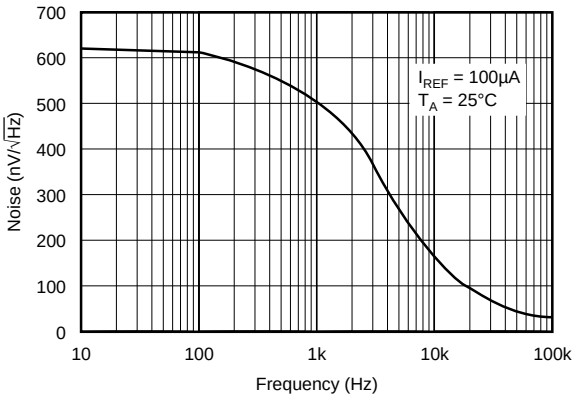
REVERSE DYNAMIC IMPEDANCE



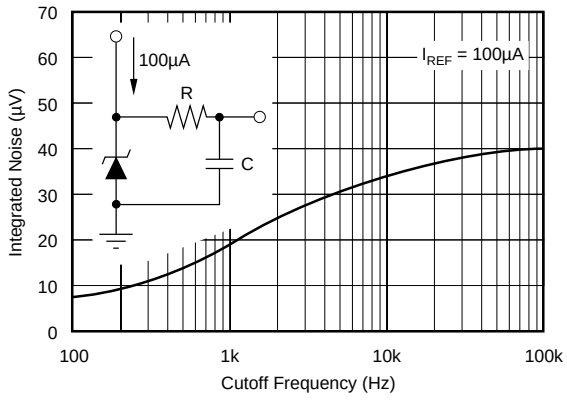
TYPICAL PERFORMANCE CURVES 1.2V (CONT)

T_A = +25°C unless otherwise noted.

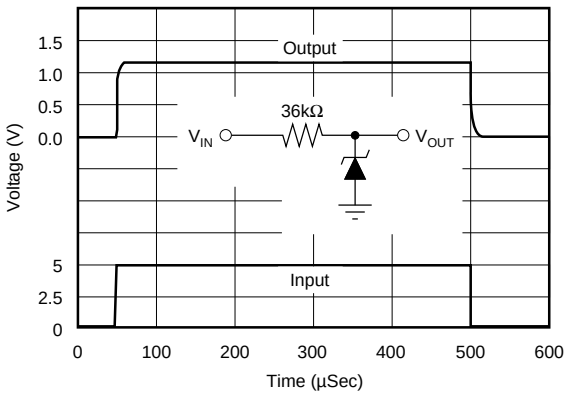
NOISE VOLTAGE



FILTERED OUTPUT NOISE



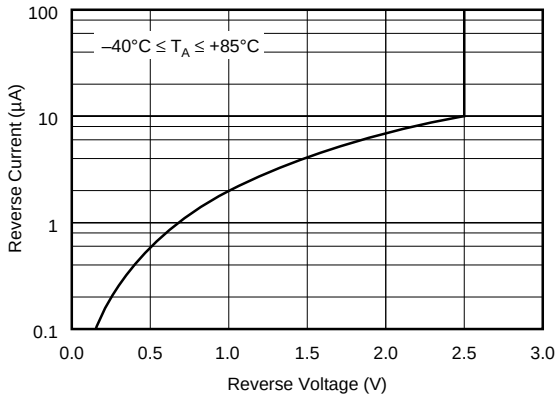
RESPONSE TIME



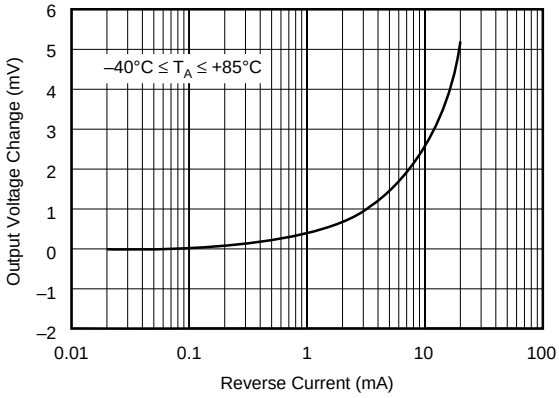
TYPICAL PERFORMANCE CURVES 2.5V

T_A = +25°C unless otherwise noted.

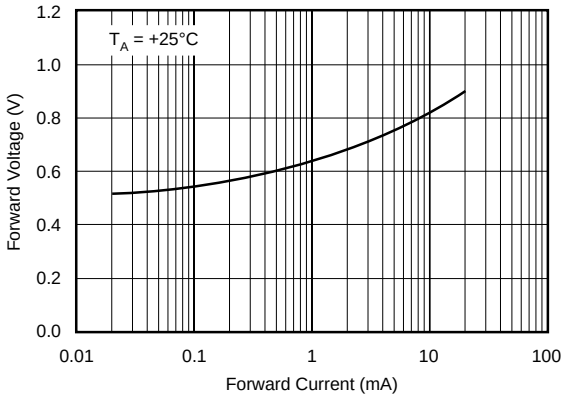
REVERSE CHARACTERISTICS



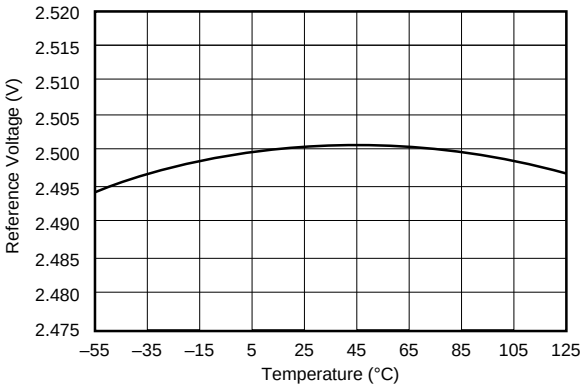
REVERSE VOLTAGE CHANGE



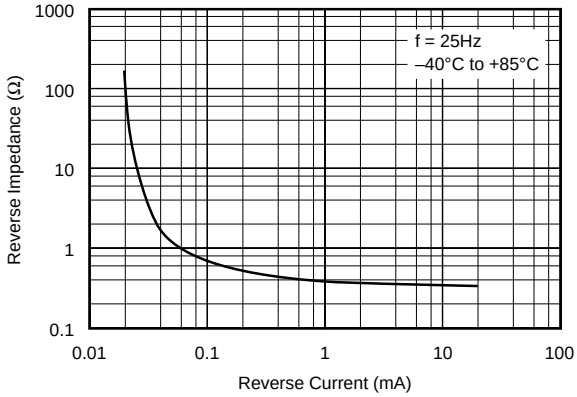
FORWARD CHARACTERISTICS



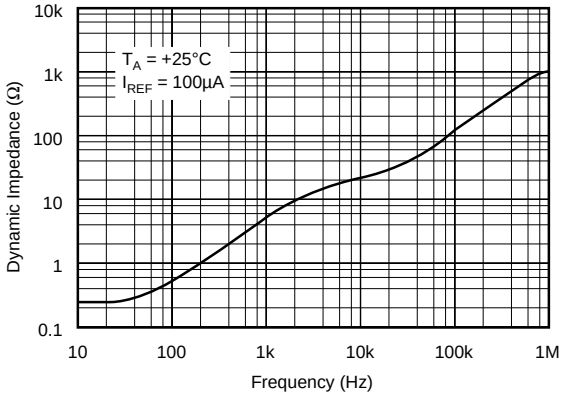
TEMPERATURE DRIFT



REVERSE DYNAMIC IMPEDANCE



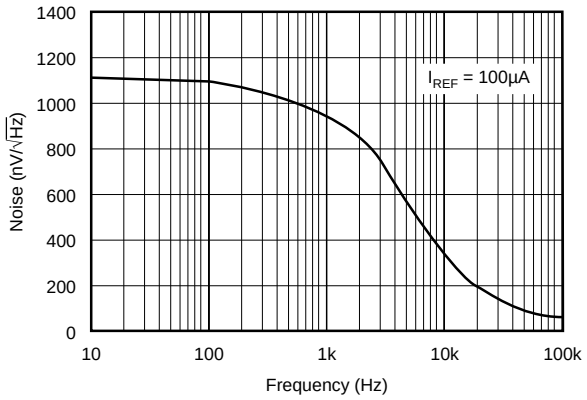
REVERSE DYNAMIC IMPEDANCE



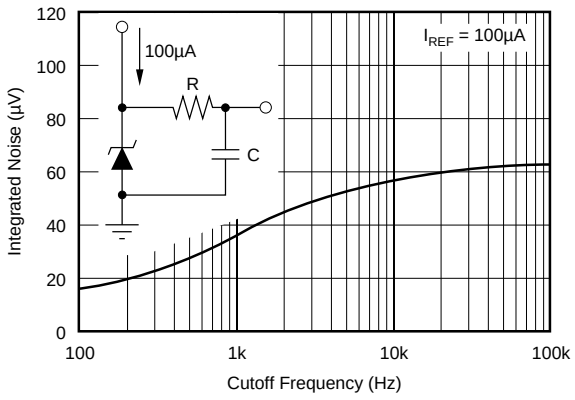
TYPICAL PERFORMANCE CURVES 2.5V (CONT)

T_A = +25°C unless otherwise noted.

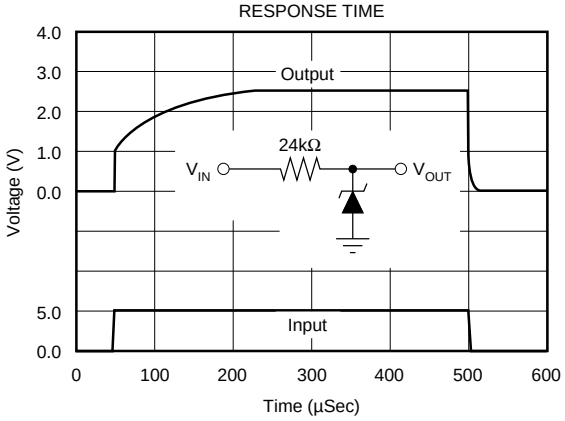
NOISE VOLTAGE



FILTERED OUTPUT NOISE



RESPONSE TIME



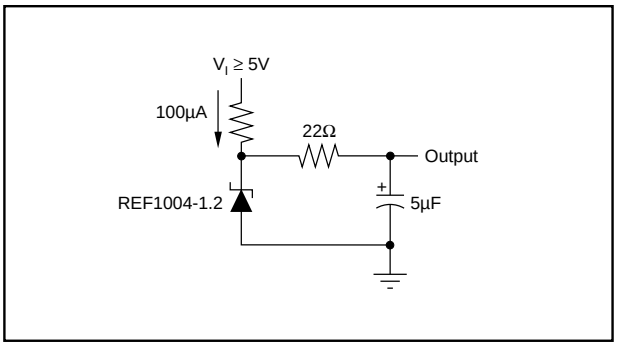


FIGURE 1. Low-Noise Reference.

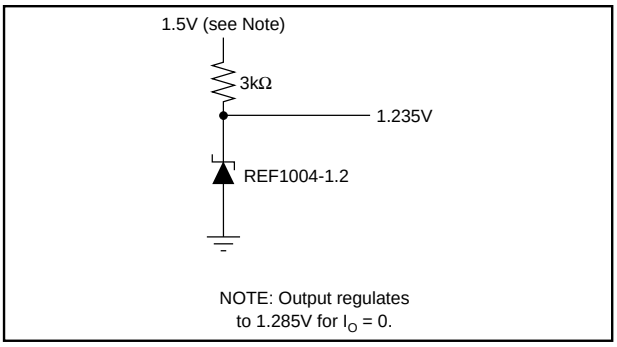


FIGURE 3. 1.2V Reference from 1.5V Battery.

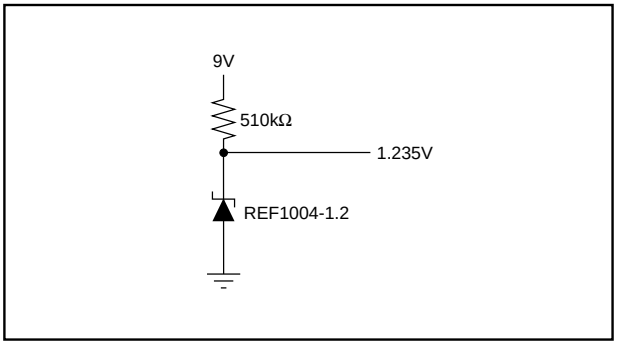


FIGURE2. Micropower Reference from 9V Battery.

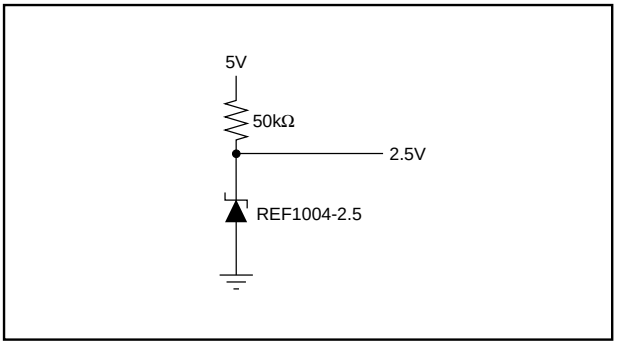


FIGURE 4. 2.5V Reference.

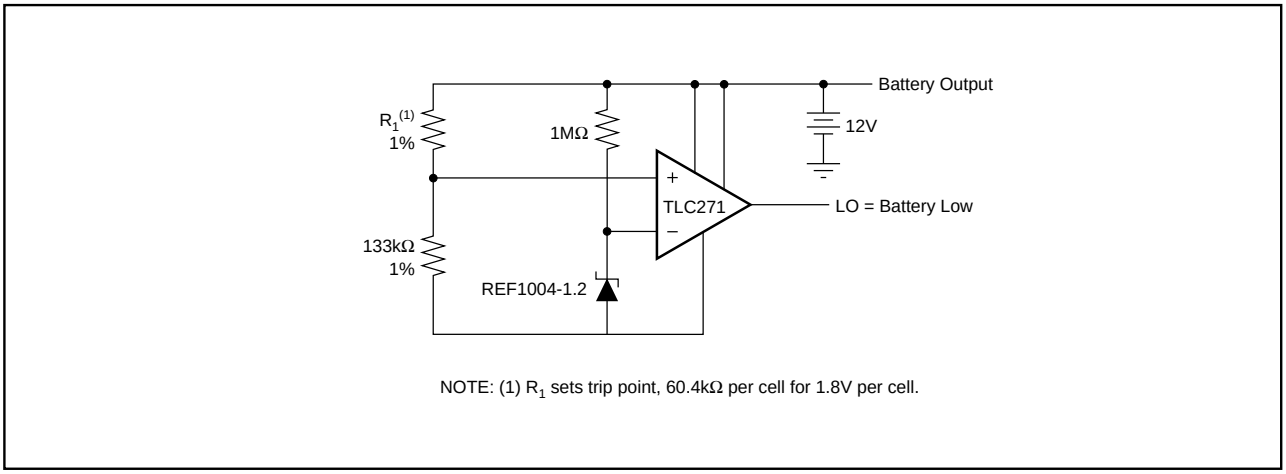


FIGURE 5. Lead-Acid Low-Battery-Voltage Detector.

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